Inventors: Park et al.

Title: Memory Cell Structures Including a Gap Filling Layer and Methods of Fabricating the Same
Attorney Docket No.: 20063/10013
Sheet 1 of 3

Fig. 1a (PRIOR ART)

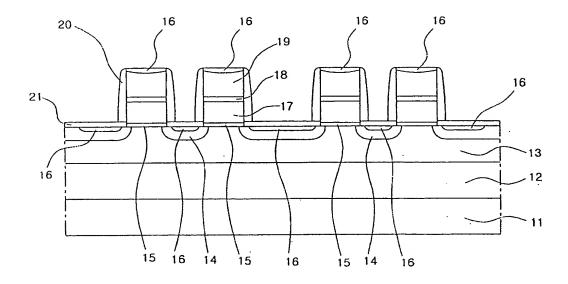


Fig. 1b (PRIOR ART)

